

# ABSTRACT

Method for fabrication of on-chip inductors and related structure are disclosed.

According to one embodiment, inductors are formed by patterning conductors within a certain dielectric layer in a semiconductor die. Thereafter, the entire dielectric layer in

the semiconductor die is subjected to a blanket implantation or sputtering of high permeability material. According to another embodiment, a first area in a semiconductor

die is covered, for example, with photoresist. A second area in the semiconductor die includes a patterned conductor which is to be used as an inductor. The patterned

conductor is also covered, for example, with photoresist. The second area, excluding the covered patterned conductor, is subjected to implantation or sputtering of high

permeability material. According to yet another embodiment, a first area of a

semiconductor die is covered, for example, with photoresist. A second area in the semiconductor area includes a patterned conductor which is to be used as an inductor.

This second area, including the patterned conductor, is subjected to implantation or

sputtering of high permeability material. The implantation or sputtering of high

permeability materials result in the inductors having much higher inductance values than they would otherwise have.